NXP ACTT6G-800E Thyristor datasheet

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AC Thyristor Triac power switch in a SOT226A (I2PAK) plastic package with selfprotective clamping capabilities against low and high energy transients.

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Product data sheet

1. General description

AC Thyristor Triac power switch in a SOT226A (I2PAK) plastic package with selfprotective clamping capabilities against low and high energy transients.

2. Features and benefits

- · Clamping structure ensuring safe high over-voltage withstand capability
- · Direct interfacing with low power drivers and microcontrollers
- Full cycle AC conduction
- Over-voltage withstand capability to IEC 61000-4-5
- Pin compatible with standard triacs
- Planar passivated for voltage ruggedness and reliability
- · Protective self turn-on capability for high energy transients
- · Safe clamping capability for low energy over-voltage transients
- Sensitive gate for easy logic level triggering
- Triggering in three quadrants only
- Very high immunity to false turn-on by dV/dt

3. Applications

- AC fan, pump and compressor controls
- Highly inductive, resistive and safety loads
- Large and small appliances (White Goods)
- Reversing induction motor controls

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	-	51	A
Tj	junction temperature		-	-	125	°C
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 108 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	6	A
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	-	2	kV





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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static chara	acteristics		I			
I _{GT}	gate trigger current	V_D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; Fig. 8	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; Fig. 8	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; Fig. 8	-	-	10	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	haracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{\text{T}(\text{RMS})} = 6 \text{ A};$ $dV_{\text{com}}/dt = 1 \text{V}/\mu\text{s}; \text{ gate open circuit};$ Fig. 14; Fig. 15	10	-	-	A/ms

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	СМ	common		LD
2	LD	load	0	G
3	G	gate		СМ
mb	LD	mounting base; load	() (003aaf296

6. Ordering information

Table 3. Ordering information							
Type number Package							
	Name	Description	Version				
ACTT6G-800E	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A				

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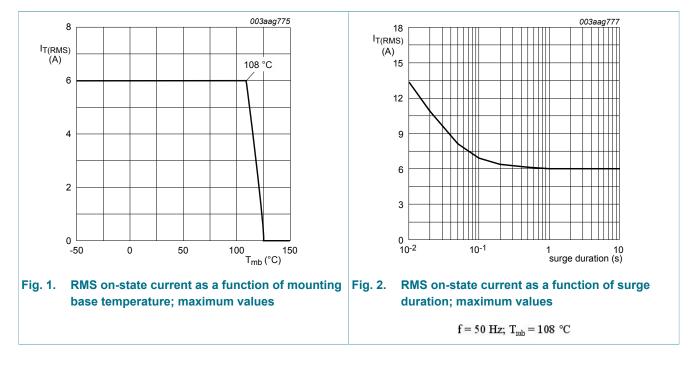
Limiting values 7.

Table 4. Limiting values

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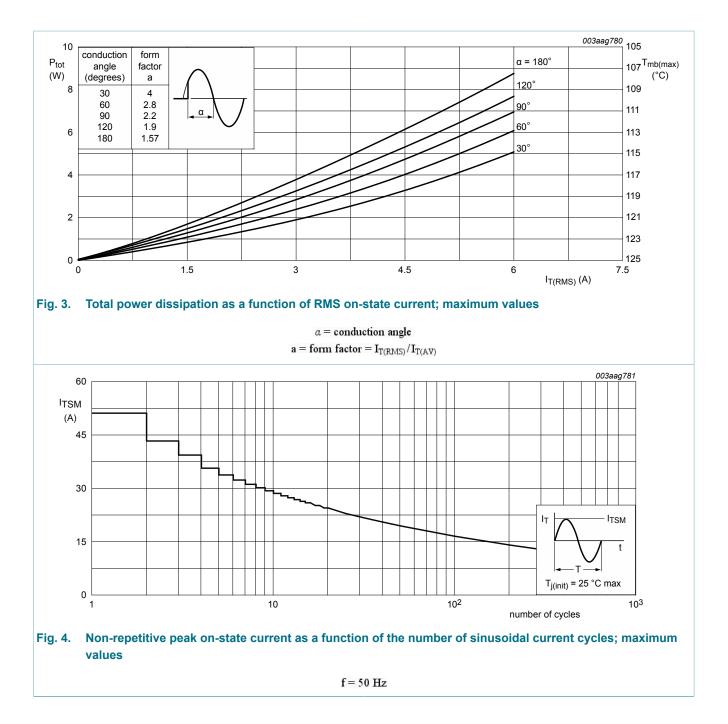
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 108 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	6	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \degree C$; $t_p = 16.7 \text{ ms}$	-	56	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	51	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	13	A ² s
dI _T /dt	rate of rise of on-state current	I_{T} = 9 A; I_{G} = 0.2 A; dI_{G}/dt = 0.2 A/µs	-	100	A/µs
I _{GM}	peak gate current	t = 20 μs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _j = 25 °C; non-repetitive, off-state; Fig. 6	-	2	kV



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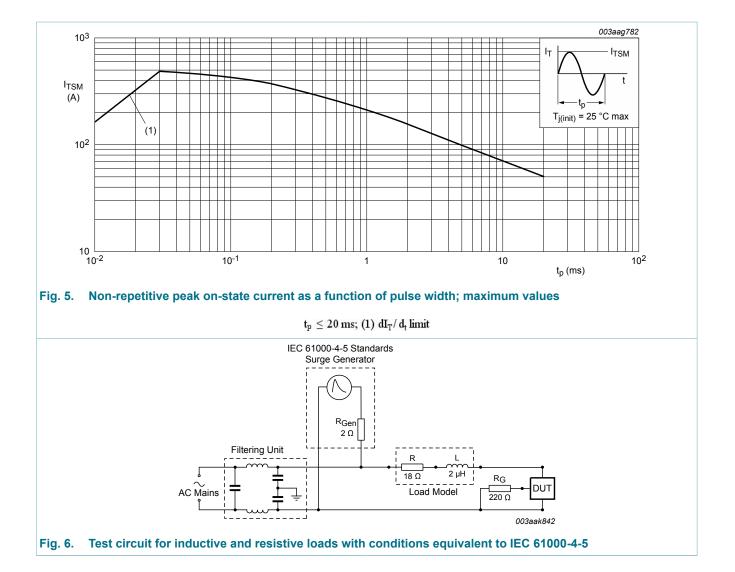
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8. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance	half cycle; Fig. 7	-	-	2.4	K/W
	from junction to mounting base	full cycle; <u>Fig. 7</u>	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

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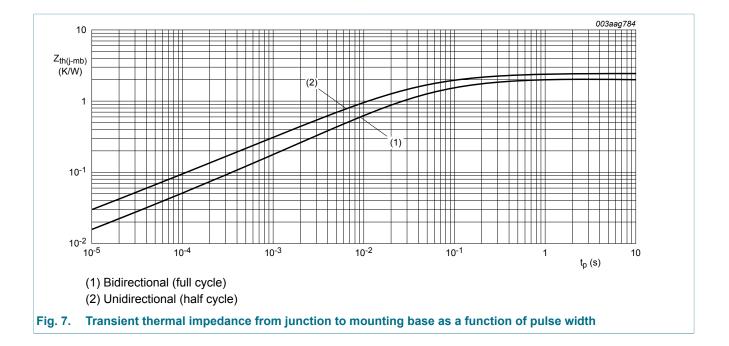
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9. Characteristics

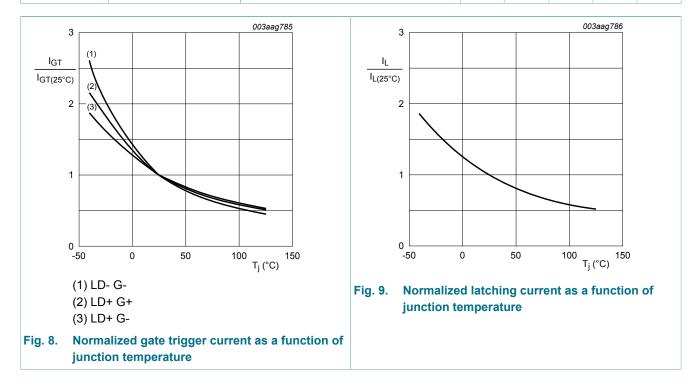
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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
ΙL	latching current	V_D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
		V_D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; Fig. 9	-	-	40	mA
		V_D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; Fig. 9	-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	25	mA
V _T	on-state voltage	I _T = 8 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; Fig. 12	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic cl	haracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dI _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{T}_\text{j} = 125 \text{ °C}; \text{I}_\text{T(RMS)} = 6 \text{ A};$ dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit; <u>Fig. 14</u> ; <u>Fig. 15</u>	3.5	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 10 V/µs; gate open circuit; <u>Fig. 14; Fig. 15</u>	5	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 6 A; dV _{com} /dt = 1 V/µs; gate open circuit; Fig. 14; Fig. 15	10	-	-	A/ms



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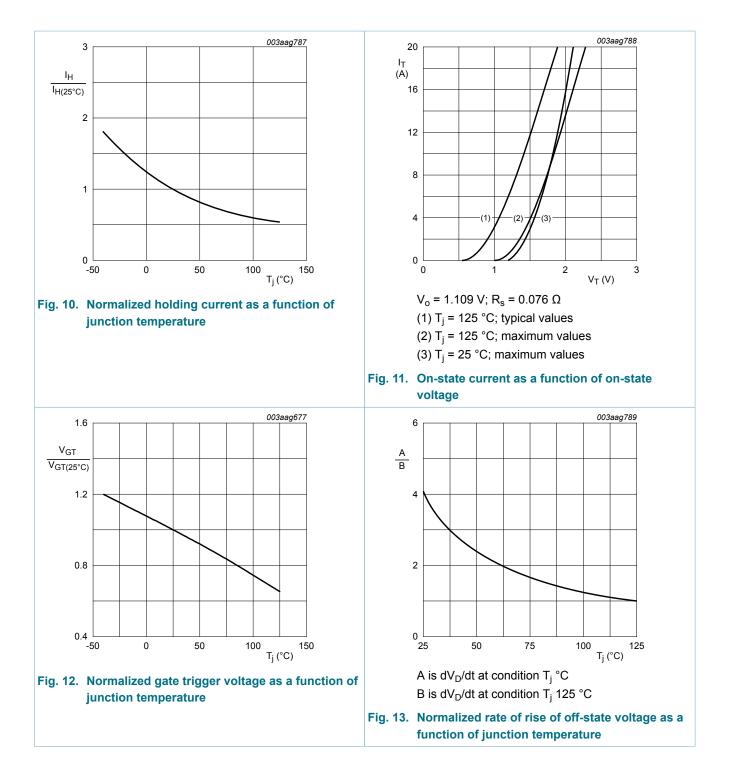
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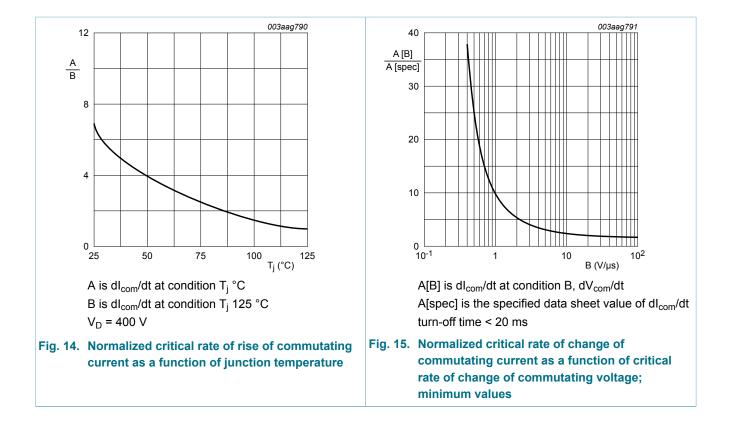
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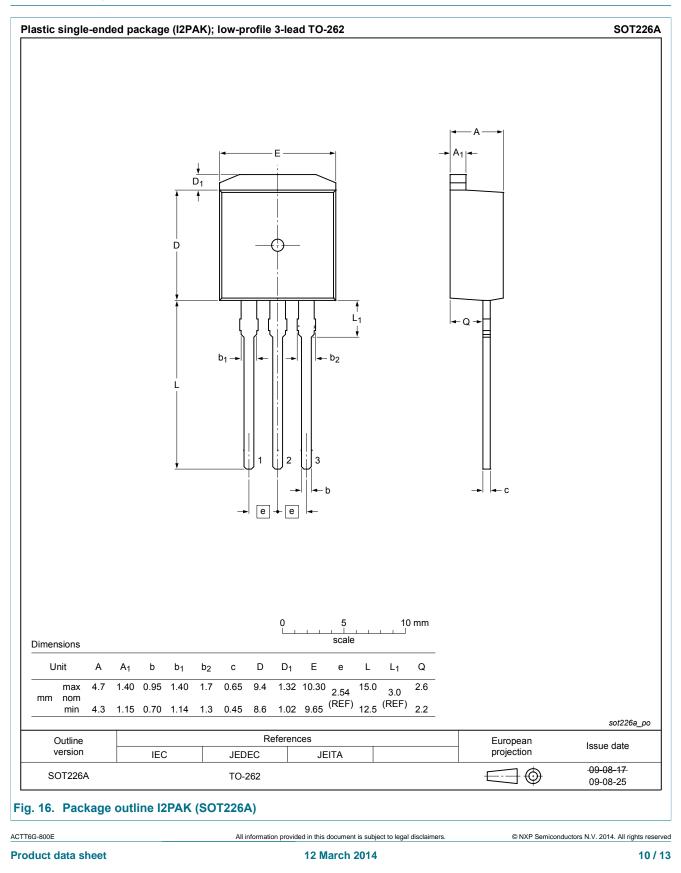
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10. Package outline



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11. Legal information

11.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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